



L Number	Hits		DB	Time stamp
1	1044	spacer same ((aluminum adj oxide) "al.sub.2	USPAT;	2003/07/16 13:38
	200	0. sub. 3")	US-PGPUB	
4	892	(spacer same ((aluminum adj oxide) "al.sub.2 O.sub.3")) not (@ad>20000830 or	USPAT; US-PGPUB	2003/07/16 11:44
		@rlad>20000830)	US-FGFUB	
7	485	spacer with ((aluminum adj oxide) "al.sub.2	USPAT;	2003/07/16 11:44
		0.sub.3")	US-PGPUB	
10	414	(spacer with ((aluminum adj oxide) "al.sub.2 0.sub.3")) not (@ad>20000830 or	USPAT;	2003/07/16 11:53
		@rlad>20000830)	US-PGPUB	
13	478	((spacer same ((aluminum adj oxide)	USPAT;	2003/07/16 11:54
		"al.sub.2 O.sub.3")) not (@ad>20000830 or	US-PGPUB	
		@rlad>20000830)) not ((spacer with		
		((aluminum adj oxide)		
16	68	(((spacer same ((aluminum adj oxide)	USPAT;	2003/07/16 11:54
;		"al.sub.2 O.sub.3")) not (@ad>20000830 or	US-PGPUB	
		@rlad>20000830)) not ((spacer with		i
		((aluminum adj oxide)		
		qate		7
19	1055	spacer same ((aluminum adj oxide) "al.sub.2	USPAT;	2003/07/16 13:38
		O.sub.3" "AlO")	US-PGPUB	
22	0	(spacer same ((aluminum adj oxide)	USPAT;	2003/07/16 13:39
		<pre>"al.sub.2 O.sub.3")) not (spacer same ((aluminum adj oxide)</pre>	US-PGPUB	
		"Alo"))		
25	11	(spacer same ((aluminum adj oxide)	USPAT;	2003/07/16 13:39
		"al.sub.2 O.sub.3" "AlO")) not (spacer same	US-PGPUB	
_	430	((aluminum adj oxide) "al.sub.2 O.sub.3")) spacer same (((aluminum adj oxide) or	HCDAM.	2002/07/16 11 22
	430	(silicon adj oxynitride) or (silicon adj	USPAT; US-PGPUB	2003/07/16 11:33
		oxide adj nitride) "al.sub.2 O.sub.3" "sion"	05 10105	
		"si.sub.\$ o.sub.\$ N.sub.\$") and ("si.sub.3		
	664	N.sub.4" "sin" or (silicon adj nitride)))	11GD 3 T	5555 (45 (55 55 55
-	064	(spacer sidewall) same (((aluminum adjoxide) or (silicon adjoxynitride) or	USPAT; US-PGPUB	2002/10/09 11:54
		(silicon adj oxide adj nitride) "al.sub.2	05 10105	
		O.sub.3" "sion" "si.sub.\$ o.sub.\$ N.sub.\$")		
		and ("si.sub.3 N.sub.4" "sin" or (silicon		
_	380	<pre>adj nitride))) ((spacer sidewall) with (gate transistor))</pre>	USPAT;	2002/10/09 11:53
	200	same (((aluminum adj oxide) or (silicon adj	US-PGPUB	2002/10/09 11:53
		oxynitride) or (silicon adj oxide adj		
		nitride) "al.sub.2 O.sub.3" "sion" "si.sub.\$		
1		o.sub.\$ N.sub.\$") and ("si.sub.3 N.sub.4" "sin" or (silicon adj nitride)))		
-	116	((spacer sidewall) with (gate transistor))	USPAT;	2002/10/09 10:25
		with (((aluminum adj oxide) or (silicon adj	US-PGPUB	,
		oxynitride) or (silicon adj oxide adj		
		nitride) "al.sub.2 O.sub.3" "sion" "si.sub.\$ O.sub.\$ N.sub.\$") with ("si.sub.3 N.sub.4"		
1		"sin" or (silicon adj nitride)))		
	264	(((spacer sidewall) with (gate transistor))	USPAT;	2002/10/09 11:34
Ī		same (((aluminum adj oxide) or (silicon adj	US-PGPUB	
		oxynitride) or (silicon adj oxide adj nitride) "al.sub.2 O.sub.3" "sion" "si.sub.\$		
		o.sub.\$ N.sub.\$") and ("si.sub.3 N.sub.4"		
		"sin" or (silicon adj nitride)))) not		
		(((spacer sidewall) with (gate transistor))		
İ		with (((aluminum adj oxide) or (silicon adj oxynitride) or (silicon adj oxide adj		
		nitride) "al.sub.2 O.sub.3" "sion" "si.sub.\$		
		o.sub.\$ N.sub.\$") with ("si.sub.3 N.sub.4"		
		"sin" or (silicon adj nitride))))		





-	413	((spacer sidewall) same (((aluminum adj	USPAT;	2002/10/09 11:54
		oxide) or (silicon adj oxynitride) or	US-PGPUB	
		(silicon adj oxide adj nitride) "al.sub.2		
		O.sub.3" "sion" "si.sub.\$ o.sub.\$ N.sub.\$")		
	1	and ("si.sub.3 N.sub.4" "sin" or (silicon		
		adj nitride)))) not (((spacer sidewall) with		
		(gate transistor)) same (((aluminum adj		
		oxide) or (silicon adj oxynitride) or	ļ	<u> </u>
		(silicon adj oxide adj nitride) "al.sub.2]
		0.sub.3" "sion" "si.sub.\$ 0.sub.\$ N.sub.\$")		
İ		and ("si.sub.3 N.sub.4" "sin" or (silicon		
		adj nitride))))		
	140	(((spacer sidewall) same (((aluminum adj	USPAT:	2002/10/09 14:42
-	149	oxide) or (silicon adj oxynitride) or	US-PGPUB	,,
		oxide) or (silicon adj oxymiciae) or	05 10102	
		(silicon adj oxide adj nitride) "al.sub.2		
		0.sub.3" "sion" "si.sub.\$ o.sub.\$ N.sub.\$")		
		and ("si.sub.3 N.sub.4" "sin" or (silicon		Į.
1		adj nitride)))) not (((spacer sidewall) with		
		(gate transistor)) same (((aluminum adj	1	1
	1	oxide) or (silicon adj oxynitride) or		
		(silicon adj oxide adj nitride) "al.sub.2		
		O.sub.3" "sion" "si.sub.\$ o.sub.\$ N.sub.\$")		
		and ("si.sub.3 N.sub.4" "sin" or (silicon		
		adj nitride))))) and (anisotropic)		
-	1	("6350665").PN.	USPAT;	2002/10/09 14:42
			US-PGPUB	
_	1	(("6350665").PN.) and ((second adj spacer)	USPAT;	2002/10/09 17:12
		with silicon)	US-PGPUB	
_	1	("5915182").PN.	USPAT;	2002/10/09 17:12
			US-PGPUB	
_	8	("4477962" "4577392" "5391508"	USPAT	2002/10/09 17:13
-		"5504024" "5736446" "5766969"		
	t	"5770507"		